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# SrO-layer insertion in Ruddlesden–Popper Sn-based perovskite enables efficient CO<sub>2</sub> electroreduction towards formate†

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Tin (Sn)-based oxides have been proved to be promising catalysts for the electrochemical CO<sub>2</sub> reduction reaction (CO<sub>2</sub>RR) to formate (HCOO<sup>−</sup>). However, their performance is limited by their reductive transformation into metallic derivatives during the cathodic reaction. This paper describes the catalytic chemistry of a Sr<sub>2</sub>SnO<sub>4</sub> electrocatalyst with a Ruddlesden–Popper (RP) perovskite structure for the CO<sub>2</sub>RR. The Sr<sub>2</sub>SnO<sub>4</sub> electrocatalyst exhibits a faradaic efficiency of 83.7% for HCOO<sup>−</sup> at −1.08 V vs. the reversible hydrogen electrode with stability for over 24 h. The insertion of the SrO-layer in the RP structure of Sr<sub>2</sub>SnO<sub>4</sub> leads to a change in the filling status of the anti-bonding orbitals of the Sn active sites, which optimizes the binding energy of \*OCHO and results in high selectivity for HCOO<sup>−</sup>. At the same time, the interlayer interaction between interfacial octahedral layers and the SrO-layers makes the crystalline structure stable during the CO<sub>2</sub>RR. This study would provide fundamental guidelines for the exploration of perovskite-based electrocatalysts to achieve consistently high selectivity in the CO<sub>2</sub>RR.

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## Introduction

The electrochemical CO<sub>2</sub> reduction reaction (CO<sub>2</sub>RR) is an attractive and sustainable approach to mitigate the greenhouse effect by storing renewable energy (e.g., solar and wind energy) in the form of chemical bonds.<sup>1–3</sup> The CO<sub>2</sub>RR can yield a variety of valuable products, among which formate (HCOO<sup>−</sup>) shows the advantages of environmental compatibility and transportability as an important raw material.<sup>4,5</sup> It is also a promising material for liquid hydrogen storage for fuel cell applications.<sup>5,6</sup> HCOO<sup>−</sup> production by the CO<sub>2</sub>RR has been proved to be predominately realized by tin(Sn)-based electrocatalysts.<sup>7–12</sup> The emerging evidence suggested that Sn oxides exhibit high activity.<sup>7,13</sup> Besides, Sn-based electrocatalysts have the advantages of low cost, abundance in the earth's crust and environmental friendliness.<sup>7–9</sup> Nevertheless, their selectivity to HCOO<sup>−</sup> would drop with the proceeding of the CO<sub>2</sub>RR due to their reductive transformation into metallic derivatives.<sup>14,15</sup> Thence, there is an

urgent need to design Sn-based oxides with consistently high selectivity.

The electrocatalytic performance of Sn-based oxides can be promoted through compositional and structural engineering, which can tune the electrical properties and coordination stability of the active sites.<sup>16–19</sup> For instance, N doping had been conducted to regulate the charge density of the Sn active sites in SnO<sub>2</sub> to enhance the selectivity towards HCOO<sup>−</sup>.<sup>19</sup> Besides, SrSnO<sub>3</sub> has been proved to show high performance for the CO<sub>2</sub>RR to HCOO<sup>−</sup> as a result of the perovskite structure.<sup>16</sup> However, the stability of SrSnO<sub>3</sub> is still not satisfactory. The deactivation mechanism of such ABO<sub>3</sub> perovskite electrocatalysts was proposed to be the surface amorphization or reconstruction during the electrocatalytic processes.<sup>20–22</sup> Therefore, effective strategies to stabilize the crystal structures of perovskites would help further enhance the performance of Sn-based electrocatalysts. The insertion of rock-salt AO-layers in Ruddlesden–Popper (RP) perovskite not only induces interlayer interaction to stabilize the crystal structure, but also optimizes the electrical properties of the active B-site.<sup>23–26</sup>

This paper describes the design and synthesis of two-dimensional layered Sr<sub>2</sub>SnO<sub>4</sub> with a RP structure for the selective conversion of CO<sub>2</sub> to HCOO<sup>−</sup>. Compared with the SnO<sub>2</sub> and SrSnO<sub>3</sub> samples, Sr<sub>2</sub>SnO<sub>4</sub> shows enhanced selectivity with the Faradaic Efficiency (FE) for HCOO<sup>−</sup> reaching 83.7% (−1.08 V vs. the reversible hydrogen electrode). Besides, Sr<sub>2</sub>SnO<sub>4</sub> exhibits long-term stability for over 24 h. As revealed by the experiments and density functional theory (DFT) calculations, the SrO-layer in the RP structure is the key to achieving good performance,

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which could optimize the binding energy of  $^*\text{OCHO}$  and promote structural stability.

## Results and discussion

### Structures of catalysts

Fig. 1a shows the X-ray diffraction (XRD) patterns of  $\text{SnO}_2$ ,  $\text{SrSnO}_3$ , and  $\text{Sr}_2\text{SnO}_4$ , the diffraction peaks of which are readily indexed to tetragonal  $\text{SnO}_2$  ( $P4_2mm$ , JCPDS No. 41-1445), cubic  $\text{SrSnO}_3$  ( $Pm3m$ , JCPDS No. 74-1298) and tetragonal  $\text{Sr}_2\text{SnO}_4$  ( $I4/mmm$ , JCPDS No. 97-002-7114), respectively. No peak corresponding to other phases was detected, demonstrating the high phase purity of  $\text{SnO}_2$ , perovskite  $\text{SrSnO}_3$ , and RP perovskite  $\text{Sr}_2\text{SnO}_4$  catalysts. The scanning electron microscopy (SEM) images reveal the porous structures of the samples (Fig. S1†). In addition, the electron dispersive X-ray spectroscopy (EDS) mappings exhibit uniform distributions of Sr, Sn, and O elements (Fig. S2 and S3†). To further confirm the formation of the RP phase, the high-resolution transmission electron microscopy (HRTEM) image of  $\text{Sr}_2\text{SnO}_4$  was collected (Fig. 1b). The observed lattice fringes with a spacing of 0.28 nm and 0.20 nm correspond to the (110) and (200) planes of  $\text{Sr}_2\text{SnO}_4$ . The inset shows the result of fast Fourier transform (FFT) analysis of the HRTEM image, which further confirms the tetragonal structure of  $\text{Sr}_2\text{SnO}_4$ . Moreover, the selected area electron diffraction (SAED) pattern of  $\text{Sr}_2\text{SnO}_4$  clearly reflects the tetragonally arranged diffraction spots of the [001] zone axes (Fig. 1c), consistent with the result of the HRTEM characterization.

Raman spectroscopy was used to investigate the differences in structures between the three Sn-based oxides (Fig. 1d). The bands centered at 472, 631 and 771  $\text{cm}^{-1}$  of  $\text{SnO}_2$  correspond to the vibration modes of  $E_g$ ,  $A_{1g}$ , and  $B_{2g}$ , respectively.<sup>27</sup> The band of  $\text{SrSnO}_3$  at 399  $\text{cm}^{-1}$  corresponds to  $\text{SnO}_3$  torsional mode, and the peak at 576  $\text{cm}^{-1}$  is associated with Sn–O stretching vibrations, indicating the formation of  $[\text{SnO}_6]$  octahedra.<sup>28,29</sup> The band of  $\text{Sr}_2\text{SnO}_4$  located at 445  $\text{cm}^{-1}$  is related to the vibration

of the bridge Sr–O–Sn oxygen bond axis in  $A_{1g}$  symmetry along the  $c$  axis. This band shows the interactions between the perovskite layers and the rock-salt SrO-layers in the RP structure.<sup>30</sup> The differences in the crystal structures of the three oxides are illustrated in Fig. 1e. For  $\text{SrSnO}_3$ ,  $\text{Sr}^{2+}$  ions occupy the A-sites, whereas  $\text{Sn}^{4+}$  ions form the corner-linked  $[\text{SnO}_6]$  octahedra at the B-sites.  $\text{Sr}_2\text{SnO}_4$  is composed of rock-salt SrO-layers and  $\text{SrSnO}_3$  perovskite layers along the crystallographic  $c$ -axis direction. This alternating layered RP structure would lead to unique structural and electrical properties, which could be beneficial for promoting electrocatalytic performance.<sup>31,32</sup>

### $\text{CO}_2\text{RR}$ performance

The  $\text{CO}_2\text{RR}$  performance was measured in a three-electrode H-type cell, with  $\text{CO}_2$ -saturated 0.5 M  $\text{KHCO}_3$  as electrolyte. The products were analysed at potentials between  $-0.88$  and  $-1.28$  V vs. the reversible hydrogen electrode (RHE). All the following potentials are referred to the RHE.  $\text{Sr}_2\text{SnO}_4$  exhibits a stable current density of up to  $30.0 \text{ mA cm}^{-2}$  at  $-1.28$  V, surpassing those of the  $\text{SrSnO}_3$  ( $22.9 \text{ mA cm}^{-2}$ ) and the  $\text{SnO}_2$  ( $17.8 \text{ mA cm}^{-2}$ ) electrocatalysts (Fig. S4a, S5a, and S6†). The FE for  $\text{HCOO}^-$  against potential over  $\text{Sr}_2\text{SnO}_4$  shows a volcano trend, which first increases from 46.5% at  $-0.88$  V to a peak value of 83.7% at  $-1.08$  V. It then decreases to 62.7% at  $-1.28$  V (Fig. 2a). The FEs for  $\text{HCOO}^-$  over  $\text{SnO}_2$  and  $\text{SrSnO}_3$  also show similar volcano trends (Fig. S4b and S5b†), but with much lower peak values (64.6% for  $\text{SrSnO}_3$  and 58.9% for  $\text{SnO}_2$ ). Besides,  $\text{Sr}_2\text{SnO}_4$  also exhibits the highest  $\text{HCOO}^-$  partial current density of  $12.4 \text{ mA cm}^{-2}$  at  $-1.08$  V compared to  $\text{SrSnO}_3$  ( $9.0 \text{ mA cm}^{-2}$ ) and  $\text{SnO}_2$  ( $5.9 \text{ mA cm}^{-2}$ ) (Fig. S7†). The stability tests were performed at a consistent potential of  $-1.08$  V (Fig. 2c).  $\text{Sr}_2\text{SnO}_4$  displays no obvious decay in the current density with the FE for  $\text{HCOO}^-$  maintained at about 79.0%. However, there is an obvious increase in the current density for  $\text{SrSnO}_3$  and  $\text{SnO}_2$ , with a decrease in  $\text{HCOO}^-$  FE at the same time. Although the

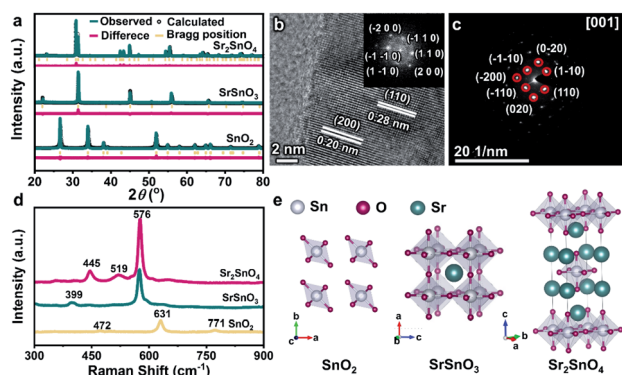


Fig. 1 (a) The XRD patterns of  $\text{SnO}_2$ ,  $\text{SrSnO}_3$ , and  $\text{Sr}_2\text{SnO}_4$  with their Rietveld refinement results. (b) HRTEM and FFT (inset) images of  $\text{Sr}_2\text{SnO}_4$ . (c) The SAED patterns along [001] of  $\text{Sr}_2\text{SnO}_4$ . (d) The Raman spectra of  $\text{SnO}_2$ ,  $\text{SrSnO}_3$ , and  $\text{Sr}_2\text{SnO}_4$ . (e) Illustrations of the crystal structures of  $\text{SnO}_2$ ,  $\text{SrSnO}_3$ , and  $\text{Sr}_2\text{SnO}_4$ . Color code: O (purple), Sr (turquoise), and Sn (gray).

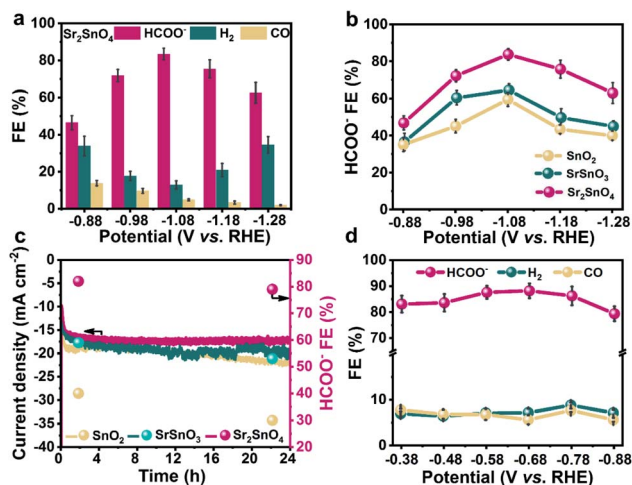


Fig. 2 (a) FEs for various products over  $\text{Sr}_2\text{SnO}_4$ . (b) FEs for  $\text{HCOO}^-$  over  $\text{SnO}_2$ ,  $\text{SrSnO}_3$  and  $\text{Sr}_2\text{SnO}_4$  at different potentials. (c) Stability tests of  $\text{SnO}_2$ ,  $\text{SrSnO}_3$  and  $\text{Sr}_2\text{SnO}_4$  at a potential of  $-1.08$  V vs. RHE. (d) FEs for various products over  $\text{Sr}_2\text{SnO}_4$  in a flow cell.

selectivity of these Sn-based electrocatalysts may not reach the high value reported in some representative studies,<sup>33,34</sup> the comparison of their performance could reflect the structural advantages of the RP perovskite. The electrocatalytic performance of  $\text{Sr}_2\text{SnO}_4$  was also evaluated in a flow cell with the catalysts dispersed on a gas diffusion electrode (GDE) to enhance the mass transfer of  $\text{CO}_2$ . The peak FE towards  $\text{HCOO}^-$  over  $\text{Sr}_2\text{SnO}_4$  is 84.5% at  $-0.68$  V (Fig. 2d), and the current density for  $\text{HCOO}^-$  reaches about  $79.2 \text{ mA cm}^{-2}$  at  $-0.88$  V (Fig. S8†). Moreover,  $\text{Sr}_2\text{SnO}_4$  displays long-term stability for over 50 h with the  $\text{HCOO}^-$  partial current density maintained at about  $59.1 \text{ mA cm}^{-2}$  (Fig. S9†). The electrolyte was replaced during the chronoamperometric test to avoid the formation of (bi)carbonate salts on the diffusion layer, which caused the strong fluctuation of current density. The FEs towards  $\text{H}_2$  and  $\text{CO}$  are below 10.0% with negligible change. According to the results of the activity evaluation, the  $\text{Sr}_2\text{SnO}_4$  with the RP perovskite structure achieved consistently high selectivity towards  $\text{HCOO}^-$ . The performance of  $\text{Sr}_2\text{SnO}_4$  is comparable to some of the state-of-the-art electrocatalysts for  $\text{HCOO}^-$  production through the  $\text{CO}_2\text{RR}$  (Table S1†).

### Operando Raman and ATR-SEIRAS spectra

To reveal the origin of the high stability of  $\text{Sr}_2\text{SnO}_4$ , *operando* Raman spectra of different samples were collected using a homemade electrochemical cell (Fig. S10†). With the decrease of the potential from  $-0.58$  V to  $-1.28$  V, the  $\text{A}_{1g}$  peak of crystalline  $\text{SnO}_2$  at  $631 \text{ cm}^{-1}$  declines in intensity, which finally disappears after  $-1.08$  V (Fig. 3a). This phenomenon would be caused by the reduction of  $\text{SnO}_2$  to metallic Sn at high cathodic potentials, as proved by the formation of the Sn phase after the  $\text{CO}_2\text{RR}$  stability test (Fig. S11a†).<sup>14</sup> In the *operando* Raman spectra of  $\text{SrSnO}_3$ , the appearance of peaks at  $631 \text{ cm}^{-1}$  below  $-1.08$  V suggests the surface reconstruction of  $\text{SrSnO}_3$  to form  $\text{SnO}_2$  during the  $\text{CO}_2\text{RR}$ , which would then be partially reduced to metallic Sn (Fig. 3b). This result could be supported by the XRD pattern of  $\text{SrSnO}_3$  after the stability test, which clearly shows the presence of  $\text{SnO}_2$  and Sn phases (Fig. S11b†).<sup>16</sup> In contrast, the Raman bands of  $\text{Sr}_2\text{SnO}_4$  at  $445 \text{ cm}^{-1}$  arising from the interactions between the perovskite layer and rock-salt SrO-layer remain unchanged at different potentials, same as the bands corresponding to the  $[\text{SnO}_6]$  octahedra at  $576 \text{ cm}^{-1}$

(Fig. 3c). These phenomena are in agreement with the end-of-test XRD pattern, showing diffraction peaks of only  $\text{Sr}_2\text{SnO}_4$  (Fig. S11c†). The HRTEM and SEM images of the three Sn-based oxide catalysts after the  $\text{CO}_2\text{RR}$  stability test have been characterized. There was a significant change in the morphology of  $\text{SnO}_2$  (Fig. S12a†). Such a change could be ascribed to the reduction of  $\text{SnO}_2$  to metallic Sn (Fig. S13†). Similar phenomena could also be found for  $\text{SrSnO}_3$ , which could be reduced to  $\text{SnO}_2$  and Sn (Fig. S12b and S14†). However, the morphology of the  $\text{Sr}_2\text{SnO}_4$  electrocatalyst was maintained after the  $\text{CO}_2\text{RR}$  stability test (Fig. S12c†). Besides, the HRTEM image showed that the crystalline nature of  $\text{Sr}_2\text{SnO}_4$  was maintained (Fig. S15†). EDS mappings of  $\text{Sr}_2\text{SnO}_4$  after the stability test exhibit uniform distributions of Sr, Sn, and O elements (Fig. S16†). The results above demonstrate the superior stability of  $\text{Sr}_2\text{SnO}_4$  during the  $\text{CO}_2\text{RR}$ . The high durability of  $\text{Sr}_2\text{SnO}_4$  would be induced by the SrO-layer insertion in the RP structure, which leads to the strong interaction between perovskite layers and rock-salt SrO-layers to prohibit structural deformation and reconstruction.<sup>26</sup>

In addition to good stability, the RP perovskite  $\text{Sr}_2\text{SnO}_4$  electrocatalyst shows high selectivity towards  $\text{HCOO}^-$ . To find the underlining mechanism of the promoted electrocatalytic performance, *operando* attenuated-total-reflection surface-enhanced infrared absorption spectroscopy (ATR-SEIRAS) characterization was conducted. The peaks at around  $1630 \text{ cm}^{-1}$  observed in all three samples can be assigned to the interfacial  $\text{H}_2\text{O}$  (Fig. 4a–c).<sup>9,35</sup> The bands at  $1367\text{--}1358 \text{ cm}^{-1}$ ,  $1397\text{--}1390 \text{ cm}^{-1}$  and  $1390\text{--}1386 \text{ cm}^{-1}$  for  $\text{SnO}_2$ ,  $\text{SrSnO}_3$  and  $\text{Sr}_2\text{SnO}_4$  with an obvious Stark effect (peak position shifted to a lower wavenumber at more negative potentials) could be assigned to  $^*\text{OCHO}$  adsorbed on the surface.<sup>36,37</sup> The  $^*\text{OCHO}$  peaks of  $\text{SnO}_2$  can be observed from  $-0.48$  V to  $-1.28$  V. For  $\text{SrSnO}_3$ , the signal of  $^*\text{OCHO}$  appears at  $-0.68$  V and disappears at  $-1.18$  V. The signal of  $^*\text{OCHO}$  was detected from  $-0.58$  V to  $-0.88$  V for  $\text{Sr}_2\text{SnO}_4$ . Since  $^*\text{OCHO}$  is the essential intermediate for the generation of  $\text{HCOO}^-$ ,<sup>38</sup> its rapid desorption on  $\text{Sr}_2\text{SnO}_4$  would be the result of the weak adsorption of  $^*\text{OCHO}$ , considering its high selectivity towards  $\text{HCOO}^-$ .<sup>39,40</sup> Therefore, the high selectivity of  $\text{Sr}_2\text{SnO}_4$  would originate from the optimized binding energy of  $^*\text{OCHO}$  on the surface, which might be realized by the SrO-layer insertion in the RP perovskite structure.

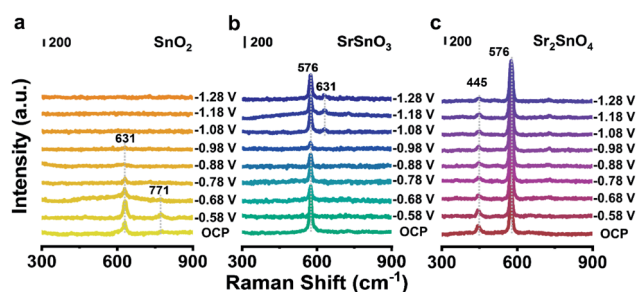


Fig. 3 *Operando* Raman spectra of (a)  $\text{SnO}_2$ , (b)  $\text{SrSnO}_3$  and (c)  $\text{Sr}_2\text{SnO}_4$  recorded at various potentials vs. RHE in a  $\text{CO}_2$ -saturated 0.5 M  $\text{KHCO}_3$  solution, respectively.

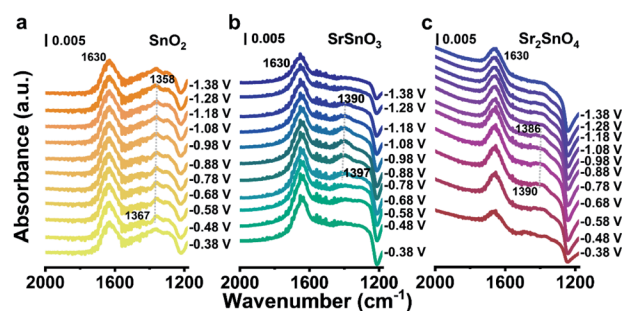


Fig. 4 *Operando* ATR-SEIRAS spectra of (a)  $\text{SnO}_2$ , (b)  $\text{SrSnO}_3$  and (c)  $\text{Sr}_2\text{SnO}_4$  recorded at various potentials vs. RHE in a  $\text{CO}_2$ -saturated 0.5 M  $\text{KHCO}_3$  solution, respectively.



## DFT simulations

To further reveal the intrinsic role of the RP structure of  $\text{Sr}_2\text{SnO}_4$  in promoting selectivity, DFT simulations were performed. Thermodynamically stable  $\text{SnO}_2(110)$ ,<sup>41</sup>  $\text{SrSnO}_3(001)$  (Table S2†) and SrO-terminated  $\text{Sr}_2\text{SnO}_4(002)$  surfaces<sup>24</sup> were chosen as the starting models for the computational study. The influence of surface vacancies, which significantly affect the surface catalytic reactions, was considered due to the relatively large energy required for the formation of bulk oxygen vacancies in these samples (Tables S3 and S4†). According to their surface phase diagrams (Fig. S17†),  $\text{SnO}_2(110)/4\text{O}_{\text{br}}\text{H}^*$ ,<sup>41</sup>  $\text{SrSnO}_3(001)/7\text{O}_{\text{v}}$  and  $\text{Sr}_2\text{SnO}_4(002)/8\text{O}_{\text{v}}$  were found to be stable in the  $\text{CO}_2\text{RR}$  process. These models were selected for the understanding of the reaction mechanism, which would represent the real active sites of the catalysts during the reaction. As shown in the well-discussed reaction pathway of the  $\text{CO}_2\text{RR}$  to  $\text{HCOO}^-$  (Fig. S18†), the  $^*\text{OCHO}$  intermediate is formed by the hydrogenation of  $\text{CO}_2$ , which subsequently produces  $\text{HCOOH}$  by the transfer of electrons and protons.<sup>41,42</sup> The results of DFT simulations show that the formation energy of  $^*\text{OCHO}$  over the  $\text{Sr}_2\text{SnO}_4(002)/8\text{O}_{\text{v}}$  surface (0.20 eV) is higher than those over the  $\text{SrSnO}_3(001)/7\text{O}_{\text{v}}$  and the  $\text{SnO}_2(110)$  (Fig. 5a). The process of  $^*\text{OCHO}$  desorption to form  $\text{HCOOH}$  on  $\text{Sr}_2\text{SnO}_4(002)/8\text{O}_{\text{v}}$  is spontaneous. However, the energy barriers for  $^*\text{OCHO}$  desorption over  $\text{SnO}_2(110)$  and  $\text{SrSnO}_3(001)/7\text{O}_{\text{v}}$  are around 0.70 eV and 0.39 eV. Therefore,  $\text{Sr}_2\text{SnO}_4$  undergoes easy desorption of  $^*\text{OCHO}$  for the  $\text{CO}_2\text{RR}$  to  $\text{HCOO}^-$ , which is in accordance with the results of the *operando* ATR-SEIRAS characterization. Besides, the  $\Delta G_{\text{H}^*}$  on  $\text{Sr}_2\text{SnO}_4(002)/8\text{O}_{\text{v}}$  is higher than those on the  $\text{SrSnO}_3(001)/7\text{O}_{\text{v}}$  and the  $\text{SnO}_2(110)$  (Fig. 5b), as reflected by the relatively low selectivity towards  $\text{H}_2$  on  $\text{Sr}_2\text{SnO}_4$  (Fig. 2a, S4b and S5b†). Since the thermodynamically stable SrO-layer in  $\text{Sr}_2\text{SnO}_4(002)$  may be involved in the reaction (Fig. S19†), its role in the  $\text{CO}_2\text{RR}$  was investigated, which would also promote  $^*\text{OCHO}$  generation

and inhibit  $\text{H}_2$  production (Fig. S20†). These results indicate that  $\text{Sr}_2\text{SnO}_4$  exhibits high selectivity due to the optimized binding strength of  $^*\text{OCHO}$ .

Furthermore, crystal orbital Hamilton population (COHP) analysis was conducted to explore how the SrO-layer insertion in  $\text{Sr}_2\text{SnO}_4$  would affect the selectivity (Fig. 5c). The anti-bonding orbitals of Sn active sites with the O atom of  $^*\text{OCHO}$  below the Fermi level ( $E_{\text{f}}$ ) imply the weakening adsorption of  $^*\text{OCHO}$  on Sn, which is most obvious on the  $\text{Sr}_2\text{SnO}_4(002)$  surface. Therefore, the filling of the anti-bonding orbitals leads to a reduction in the bonding strength of Sn–O, corresponding to the relatively weak adsorption strength of  $^*\text{OCHO}$  on  $\text{Sr}_2\text{SnO}_4$ . Besides, the linear relationship between the integrated COHP (iCOHP) and  $\Delta G_{^*\text{OCHO}}$  quantitatively confirms that the population of bonding/antibonding orbitals below  $E_{\text{f}}$  is the key factor in regulating the  $\Delta G_{^*\text{OCHO}}$  (Fig. 5d).<sup>41</sup> Therefore, the tuned electrical properties of active sites in the RP perovskite  $\text{Sr}_2\text{SnO}_4$  electrocatalyst optimize the binding energy of  $^*\text{OCHO}$  over  $\text{Sr}_2\text{SnO}_4(002)/8\text{O}_{\text{v}}$ , leading to the high selectivity for the  $\text{CO}_2\text{RR}$  to  $\text{HCOO}^-$ .

## Conclusions

In summary, a  $\text{Sr}_2\text{SnO}_4$  perovskite electrocatalyst with a RP structure was fabricated *via* a simple solid-state reaction.  $\text{Sr}_2\text{SnO}_4$  exhibits high performance for the  $\text{CO}_2\text{RR}$  with an FE of 83.7% towards  $\text{HCOO}^-$  and long-term durability of over 24 h. The SrO-layer insertion in the RP structure leads to strong interlayer interactions, which could prohibit structural deformation and reconstruction. Thus,  $\text{Sr}_2\text{SnO}_4$  possesses good stability. Besides, the anti-bonding orbital filling of the Sn active site in the RP structure results in the favorable binding strength of  $^*\text{OCHO}$  on  $\text{Sr}_2\text{SnO}_4$ , so that it shows higher selectivity towards  $\text{HCOO}^-$  than the  $\text{SnO}_2$  and the  $\text{SrSnO}_3$  control samples. Our work demonstrates that  $\text{Sr}_2\text{SnO}_4$  can serve as an efficient electrocatalyst for  $\text{HCOO}^-$  production through the  $\text{CO}_2\text{RR}$ . The findings would guide the rational design of perovskite-based electrocatalysts and open up an avenue for tuning the catalytic selectivity and stability by structure engineering.

## Data availability

The data that supports the findings of this study is available from the corresponding author upon reasonable request.

## Author contributions

J. L. G supervised the project. P. Z. and J. Z. conceived the idea. J. Z. synthesized the catalysts and conducted the  $\text{CO}_2\text{RR}$  performance tests. L. L. L conducted DFT simulations. Y. T. H., G. H., and G. Z. conducted related characterization studies. All the authors participated in the writing of the manuscript.

## Conflicts of interest

There are no conflicts to declare.

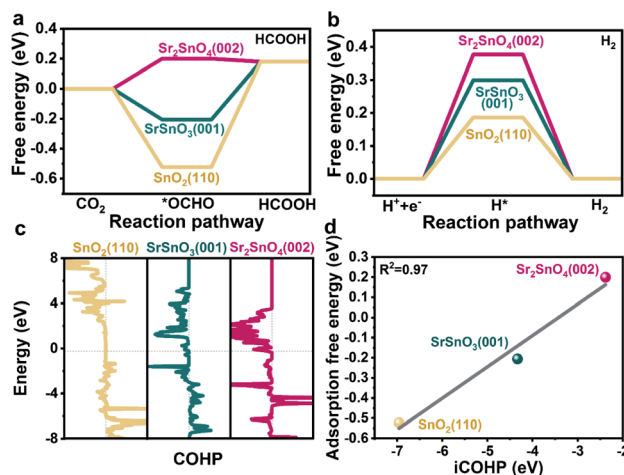


Fig. 5 The calculated free energy for (a)  $\text{HCOOH}$  and (b)  $\text{H}_2$ . (c) COHP curves of Sn active sites on  $\text{SnO}_2(110)$ ,  $\text{SrSnO}_3(001)$ , and  $\text{Sr}_2\text{SnO}_4(002)$  with O of  $^*\text{OCHO}$  interaction. (d) The correlation between the iCOHP and adsorption free energy of  $^*\text{OCHO}$  on  $\text{SnO}_2(110)$ ,  $\text{SrSnO}_3(001)$ , and  $\text{Sr}_2\text{SnO}_4(002)$ .



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